

Morphology And Luminescence Characteristics of Yttriumdisilicate Doped with Yb³⁺, Er³⁺(Ho³⁺) and Tm³⁺

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Extended Abstract

The nanomaterials doped with optically active ions have attracted considerable attention, and most of the studies in the literature devoted to the fabrication and characterization of these materials due to their potential application in photonics and optoelectronics. This interest on such host materials steadily increased with the development of new and cheap synthetic methods. [1-3].

The host lattice of yttrium silicate (SiO₂-Y₂O₃ binary system) shows a high refractory property, chemical stability. The host lattice of yttriumdisilicate (Y₂Si₂O₇) shows a high thermal and chemical stability. It has been shown that the structural phases due to its complex high temperature polymorphism are in the γ , α , β , γ , and δ forms [4-7]. In this study, RE³⁺:Y₂Si₂O₇ nanopowders were synthesized in the phase diagram of SiO₂-Y₂O₃ binary system using the sol-gel method to obtain alpha phases.

The Y₂Si₂O₇ activated with triple RE³⁺: (Yb³⁺:Er³⁺: Tm³⁺ and Yb³⁺: Ho³⁺: Tm³⁺) was successfully synthesized using the sol-gel technique. The diffuse reflections spectra of the triple doped Y₂Si₂O₇ samples in the range of 400-1050 nm were taken. The absorption bands appearing with appreciable intensity correspond to transitions from the ground state of the RE³⁺ ions to different excited states of them.

Up-converted green and red emissions were obtained in visible region from Yb³⁺:Er³⁺(Ho³⁺):Tm³⁺ doped Y₂Si₂O₇ nanopowders on excitation by a 950 nm diode laser. In the Yb³⁺:Er³⁺:Tm³⁺ doped Y₂Si₂O₇ nanopowders, the green emissions around 525 nm and 547 nm were attributed to the ²H_{11/2} → ⁴I_{15/2} and ⁴S_{3/2} → ⁴I_{15/2} transitions of the Er³⁺ ions, respectively. The strong red emission around 663 nm and 692 nm were attributed to the ⁴F_{9/2} → ⁴I_{15/2} transition of Er³⁺ ions and the ³F_{2,3} → ³H₆ transition of Tm³⁺ respectively. In the Yb³⁺:Er³⁺:Ho³⁺ doped Y₂Si₂O₇ nanopowders, the green emissions around 530 and 560 nm were attributed to the ⁵F₄ → ⁵I₈ and ⁵S₂ → ⁵I₈ transitions of the Ho³⁺ ions, respectively. The red emission around 670 nm was attributed to the ⁵F₅ → ⁵I₈ transition of Ho³⁺ ions and ³F_{2,3} → ³H₆ transition of Tm³⁺ ions. The near infrared emission around 800 nm was also attributed to ³H₄ → ³H₆ transition of Tm³⁺ ions.

In order to understand the up conversion mechanisms of the observed emission bands, the up conversion emission intensity was measured as a function of excitation power. The calculated results indicated that slopes value of triple doped α -Y₂Si₂O₇ nanoparticles showed that the up conversion mechanism corresponding to green and red emissions occurred via two-photon transitions.

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